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# LED Display Product Data Sheet LTP-2N57M

Spec No.: DS-30-95-174

Effective Date: 02/26/2002

Revision: -

**LITE-ON DCC**

**RELEASE**

BNS-OD-FC001/A4

**FEATURES**

- \* 2.0 inch (50.8 mm) MATRIX HEIGHT.
- \* LOW POWER REQUIREMENT.
- \* SINGLE PLANE, WIDE VIEWING ANGLE.
- \* SOLID STATE RELIABILITY.
- \* 5x7 ARRAY WITH X-Y SELECT.
- \* COMPATIBLE WITH USASCII AND EBCDIC CODES.
- \* STACKABLE HORIZONTALLY.
- \* CATEGORIZED FOR LUMINOUS INTENSITY.

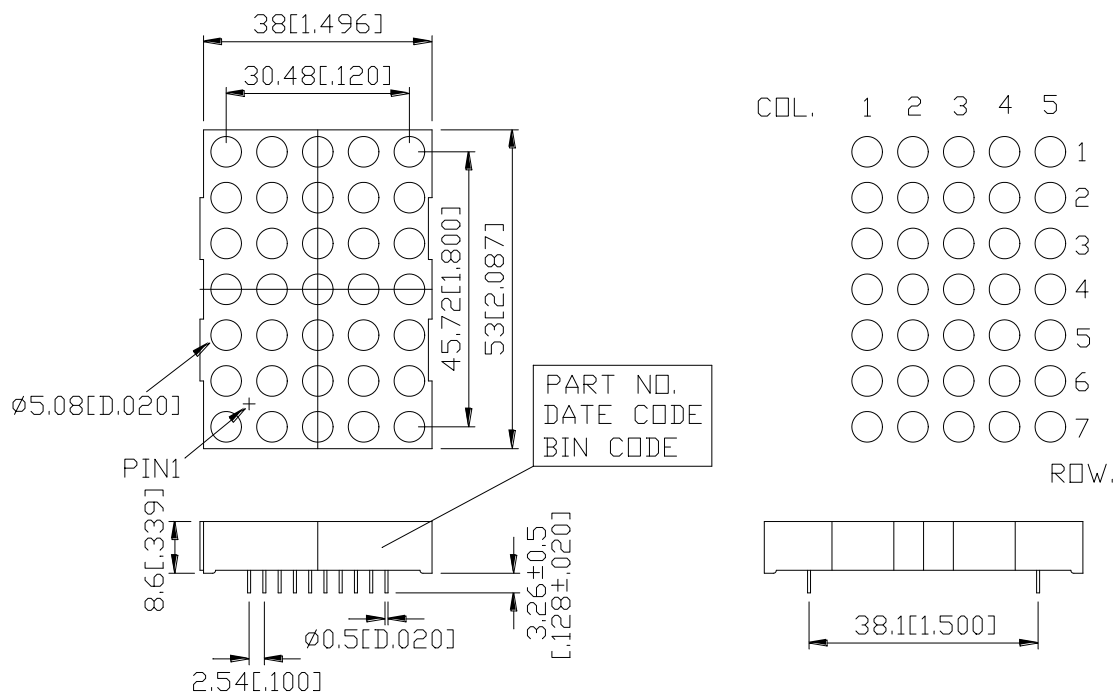
**DESCRIPTION**

The LTP-2N57M is a 2.0 inch (50.8 mm) matrix height 5 x7 dot matrix display. This device is multi-color applicable display. The green LED chips, which are made from GaP on GaP substrate. The red orange LED chips, which are made from GaAsP on GaP substrate. The device has gray face and white dot color.

**DEVICE**

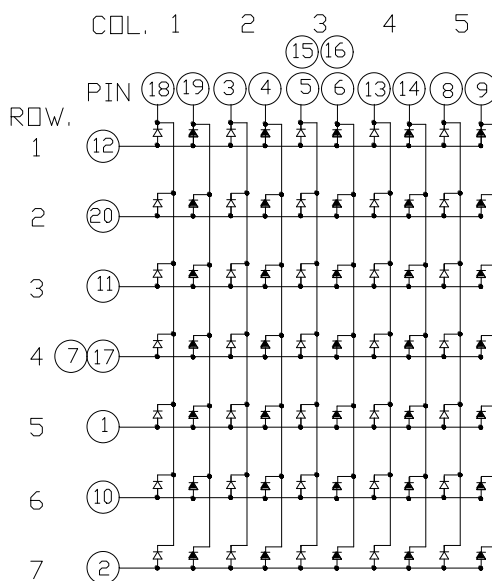
<b>PART NO.</b>	<b>DESCRIPTION</b>
MULTI-COLOR	Anode Row
LTP-2N57M	Cathode Column

## PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are  $\pm 0.25$  mm (0.01") unless otherwise noted.

## INTERNAL CIRCUIT DIAGRAM



NOTES: 1.The sign "  $\uparrow$  " stands for red orange chips  
 2.The sign "  $\nabla$  " stands for green chips

**PIN CONNECTION**

NO	CONNECTION	NO	CONNECTION
1	ANODE ROW 5	11	ANODE ROW 3
2	ANODE ROW 7	12	ANODE ROW 1
3	CATHODE COLUMN 2 GREEN	13	CATHODE COLUMN 4 GREEN
4	CATHODE COLUMN 2 RED ORANGE	14	CATHODE COLUMN 4 RED ORANGE
5	CATHODE COLUMN 3 GREEN	15	CATHODE COLUMN 3 GREEN
6	CATHODE COLUMN 3 RED ORANGE	16	CATHODE COLUMN 3 RED ORANGE
7	ANODE ROW 4	17	ANODE ROW 4
8	CATHODE COLUMN 3 GREEN	18	CATHODE COLUMN 1 GREEN
9	CATHODE COLUMN 3 RED ORANGE	19	CATHODE COLUMN 1 RED ORANGE
10	ANODE ROW 6	20	ANODE ROW 2

**ABSOLUTE MAXIMUM RATING AT Ta=25°C**

PARAMETER	GREEN	UNIT
Average Power Dissipation Per Dot	36	mW
Peak Forward Current Per Dot	100	mA
Average Forward Current Per Dot	13	mA
Derating Linear From 25°C Per Dot	0.17	mA/°C
Reverse Voltage Per Dot	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm[1/16inch] below seating plane.		

**ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C****GREEN**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I <sub>v</sub>	1780	4000		μcd	I <sub>p</sub> =80mA 1/16Duty
Peak Emission Wavelength	λ <sub>p</sub>		565		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		30		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		569		nm	I <sub>F</sub> =20mA
Forward Voltage any Dot	V <sub>F</sub>		2.1	2.6	V	I <sub>F</sub> =20mA
			3.0	3.7		I <sub>F</sub> =80mA
Reverse Current any Dot	I <sub>R</sub>			100	μA	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>v</sub> -m			2:1		I <sub>p</sub> =80mA 1/16Duty

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision International De L'Eclairage) eye-response curve.

**ABSOLUTE MAXIMUM RATING AT Ta=25°C**

PARAMETER	RED ORANGE	UNIT
Average Power Dissipation Per Dot	36	mW
Peak Forward Current Per Dot	100	mA
Average Forward Current Per Dot	13	mA
Derating Linear From 25°C Per Dot	0.17	mA/°C
Reverse Voltage Per Dot	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm[1/16inch] below seating plane.		

**ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C****RED ORANGE**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I <sub>v</sub>	1780	4000		μcd	I <sub>p</sub> =80mA 1/16Duty
Peak Emission Wavelength	λ <sub>p</sub>		630		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		40		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		621		nm	I <sub>F</sub> =20mA
Forward Voltage any Dot	V <sub>F</sub>		2.0	2.6	V	I <sub>F</sub> =20mA
			2.6	3.4		I <sub>F</sub> =80mA
Reverse Current any Dot	I <sub>R</sub>			100	μA	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio	I <sub>v</sub> -m			2:1		I <sub>p</sub> =80mA 1/16Duty

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision International De L'Eclairage) eye-response curve.

## TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

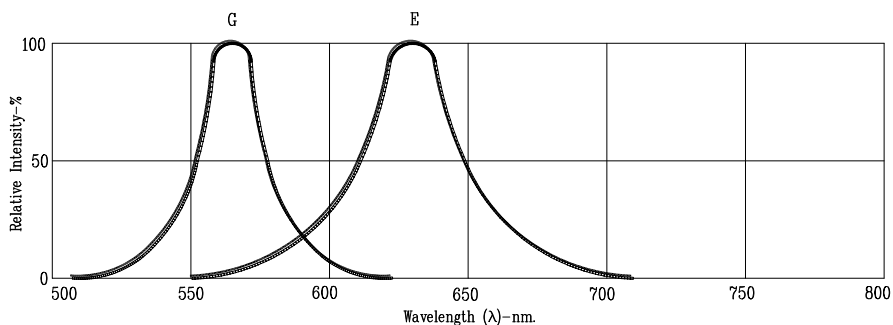


Fig1. RELATIVE INTENSITY VS. WAVELENGTH

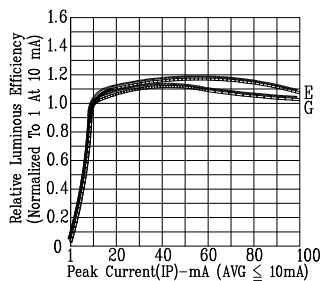


Fig2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT (REFRESH RATE 1KHz)

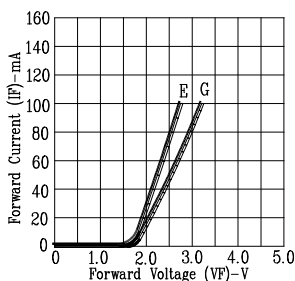


Fig3. FORWARD CURRENT VS. FORWARD VOLTAGE

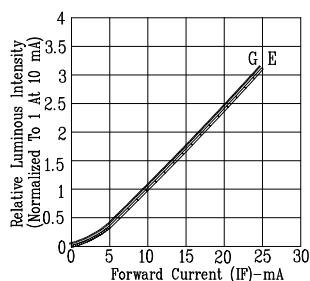


Fig4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

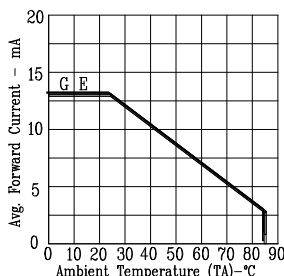


Fig5. MAX. AVERAGE FORWARD CURRENT VS. AMBIENT TEMPERATURE.

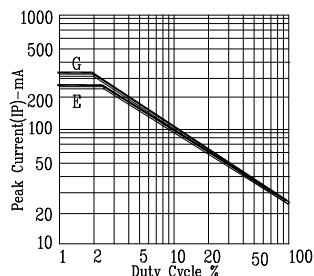


Fig6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

NOTE: G=GREEN E=RED ORANGE